

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,098,123 B2
APPLICATION NO. : 10/780244
DATED : August 29, 2006
INVENTOR(S) : Heo et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the Title Page:

Add

-- (30) **Foreign Application Priority Data**

Feb. 19, 2003 (KR)2003-0010403 --

Column 7,

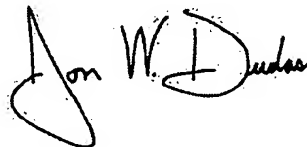
Line 57 should read -- layer comprises tungsten nitride (WN) or titanium nitride (TiN). --

Column 8,

Line 23 should read -- forming a capping layer on the metal gate layer. --

Signed and Sealed this

Ninth Day of January, 2007



JON W. DUDAS
Director of the United States Patent and Trademark Office